

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C unless otherwise stated)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			60	V
I _{F(RMS)}	Forward rms current			10	A
I _{F(AV)}	Average forward current, $\delta = 0.5$, square wave	T _c = 135 °C ⁽¹⁾	Per diode	7.5	A
			Per device	15	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal		75	A
P _{ARM}	Repetitive peak avalanche power	t _p = 10 μs, T _j = 125 °C		265	W
T _{stg}	Storage temperature range			-65 to +175	°C
T _j	Maximum operating junction temperature ⁽²⁾			150	°C

1. Value based on $R_{th(j-c)}$ max (per diode)

2. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistances

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	4	°C/W
		Total	2.4	
$R_{th(c)}$	Coupling		0.7	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$			200	μA
		$T_j = 125\text{ °C}$			45	60	mA
$V_F^{(1)}$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 7.5\text{ A}$			0.62	V
		$T_j = 125\text{ °C}$			0.52	0.57	
		$T_j = 25\text{ °C}$	$I_F = 12\text{ A}$			0.76	
		$T_j = 125\text{ °C}$			0.62	0.68	
		$T_j = 25\text{ °C}$	$I_F = 15\text{ A}$			0.82	
		$T_j = 125\text{ °C}$			0.66	0.72	

1. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.32 \times I_{F(AV)} + 0.027 I_{F(RMS)}^2$$

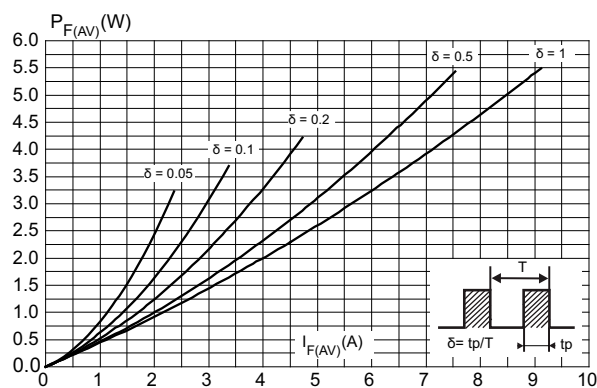
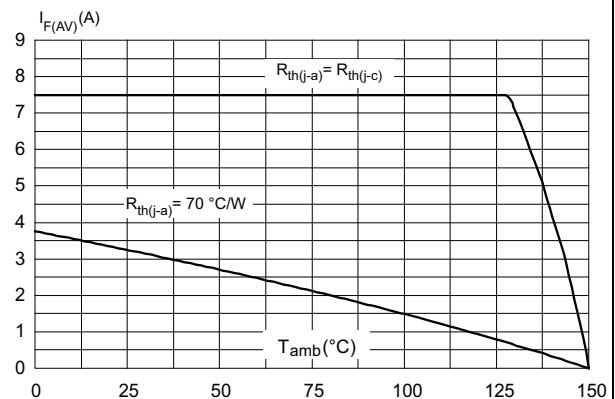
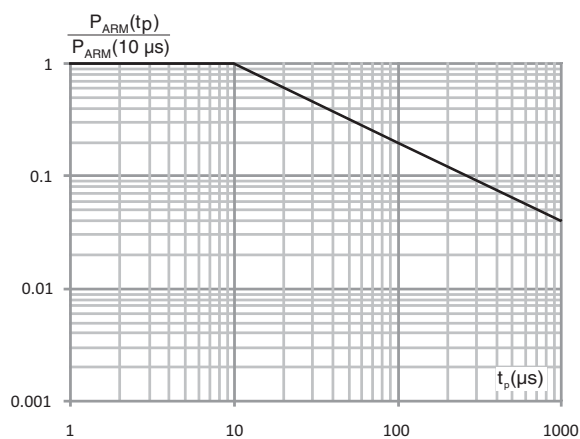
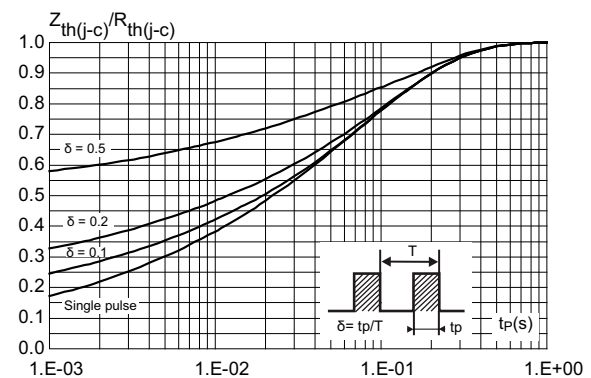
Figure 1. Average forward power dissipation versus average forward current (per diode)**Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$)(per diode)****Figure 3. Normalized avalanche power derating versus pulse duration at $T_j = 125^\circ\text{C}$** **Figure 4. Relative variation of thermal impedance junction to case versus pulse duration**

Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)

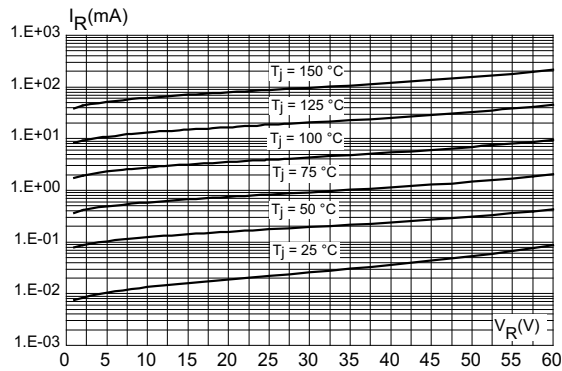


Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

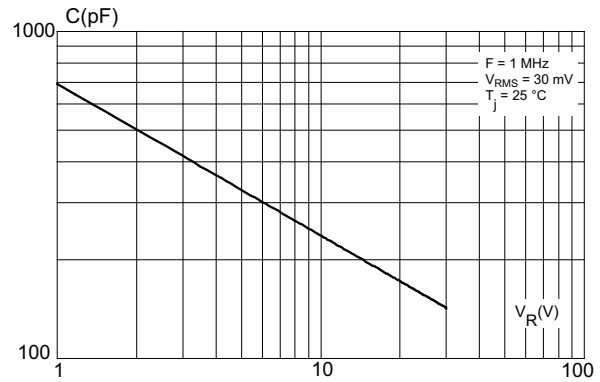


Figure 7. Forward voltage drop versus forward current (per diode)

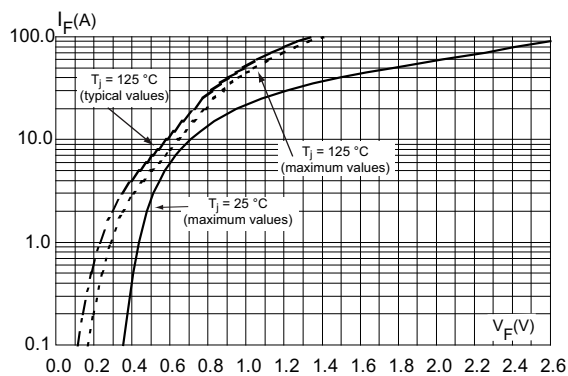
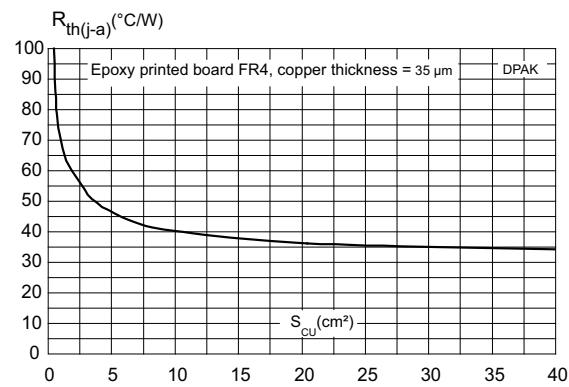


Figure 8. Thermal resistance junction to ambient versus copper surface under tab



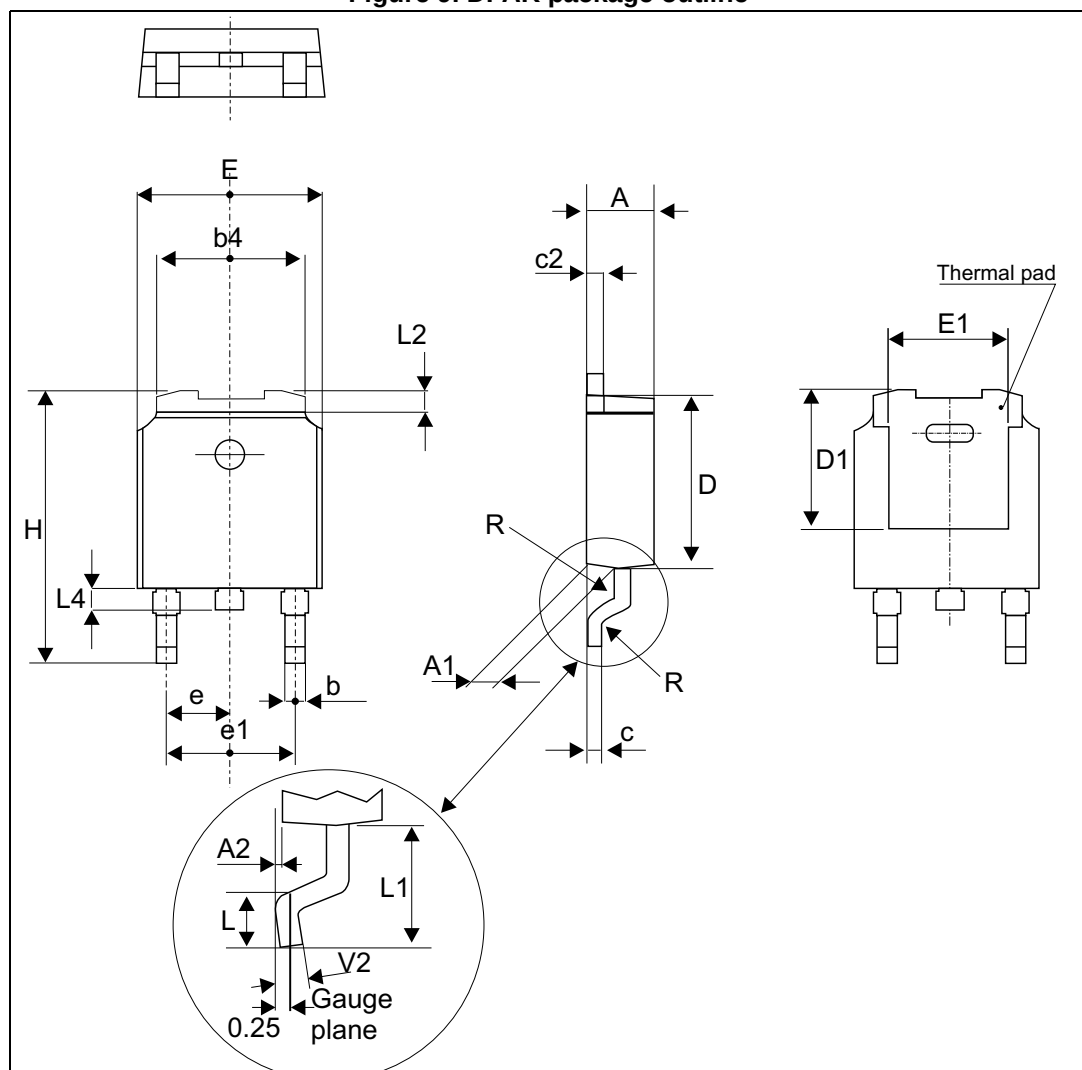
2 Package Information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 DPAK package information

Figure 9. DPAK package outline

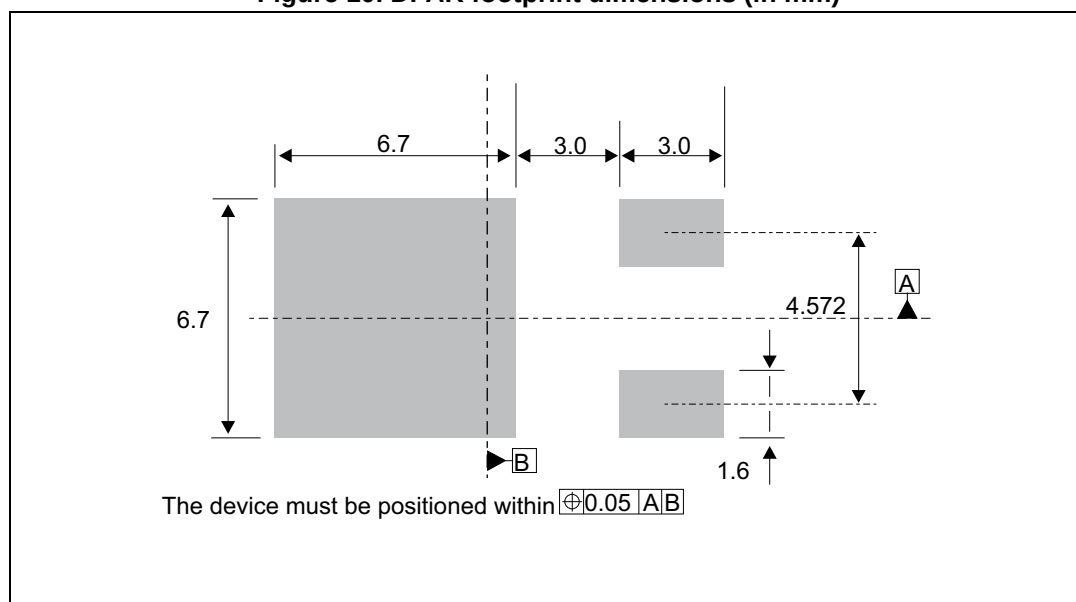


Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 5. DPAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.18		2.40	0.085		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
b	0.64		0.90	0.025		0.035
b4	4.95		5.46	0.194		0.214
c	0.46		0.61	0.018		0.024
c2	0.46		0.60	0.018		0.023
D	5.97		6.22	0.235		0.244
D1	4.95		5.60	0.194		0.220
E	6.35		6.73	0.250		0.264
E1	4.32		5.50	0.170		0.216
e		2.28			0.090	
e1	4.40		4.70	0.173		0.185
H	9.35		10.40	0.368		0.409
L	1.00		1.78	0.039		0.070
L2			1.27			0.050
L4	0.60		1.02	0.023		0.040
V2	-8°		+8°	-8°		8°

Figure 10. DPAK footprint dimensions (in mm)



3 Ordering Information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS15L60CB	S15L60C	DPAK	0.32 g	75	Tube
STPS15L60CB-TR	S15L60C	DPAK	0.32 g	2500	Tape and reel

4 Revision history

Table 7. Document revision history

Date	Revision	Description of Changes
27-Jun-2012	2	Automatic revalidation date workflow started.
07-Jan-2015	3	Updated DPAK package information and reformatted to current standard.
18-Dec-2015	4	Updated DPAK package information and reformatted to current standard.

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